

RJE0621JSP

–60V, –2A, P Channel Thermal FET Power Switching

R07DS1419EJ0100 Rev.1.00 Jun 04, 2018

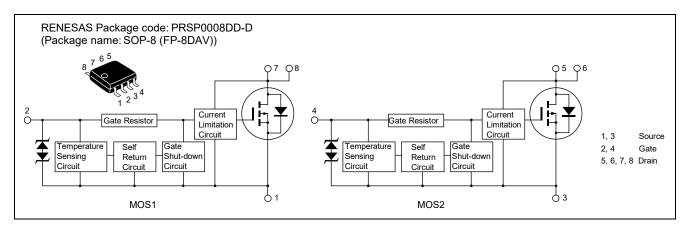
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (3 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Hysteresis type shut down operation.
- High density mounting.
- Built-in the current limitation circuit.
- Power supply voltage applies 12 V and 24 V.
- AEC-Q101compliant.

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	-60	V
Gate to source voltage	V _{GSS}	-16	V
Gate to source voltage	V _{GSS}	2.5	V
Drain current	I _D Note4	-2	Α
Body-drain diode reverse drain current	I _{DR}	-2	Α
Avalanche current	I _{AP} Note 3	-0.9	Α
Avalanche energy	E _{AR} Note 3	69	mJ
Channel dissipation	Pch Note 1	2	W
Channel dissipation	Pch Note 2	1.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. 1 Drive operation : When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW ≤ 10 s

- 2. 2 Drive operation: When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW ≤ 10 s
- 3. Tch = 25° C, Rg $\geq 50 \Omega$
- 4. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	VIH	-3	_	_	V	
	V _{IL}		_	-1.2	V	
Input current	I _{IH1}	1	_	-100	μA	Vi = -8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}		_	-50	μA	$Vi = -3.5 V, V_{DS} = 0$
	I _{IL}		_	-10	μA	$Vi = -1.2 V, V_{DS} = 0$
Input current	I _{IH(sd)1}		-0.8	_	mA	$Vi = -8 V, V_{DS} = 0$
(Gate shut down)	I _{IH(sd)2}		-0.35	_	mA	$Vi = -3.5 V, V_{DS} = 0$
Shut down temperature	Tsd		175	_	°C	Channel temperature
Return temperature	Thr		145	_	°C	Channel temperature
Gate operation voltage	Vop	-3	_	-12	V	
Drain current	I _{D limt}	-2			Α	$V_{GS} = -12 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 5}}$
(Current limitation value)		-2				

Notes: 5. Pulse test

Electrical Characteristics

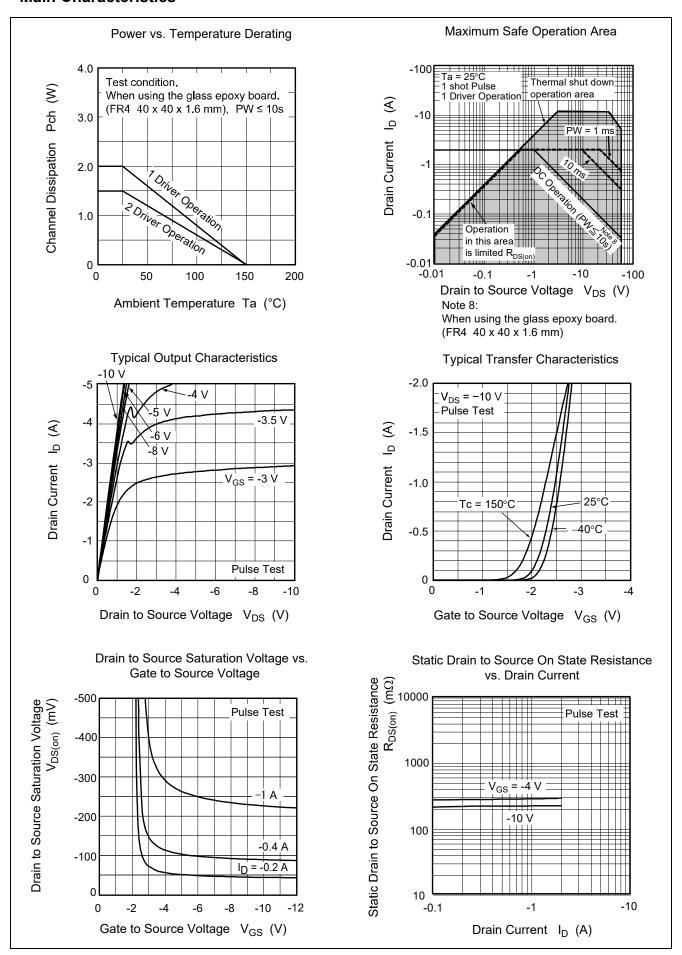
 $(Ta = 25^{\circ}C)$

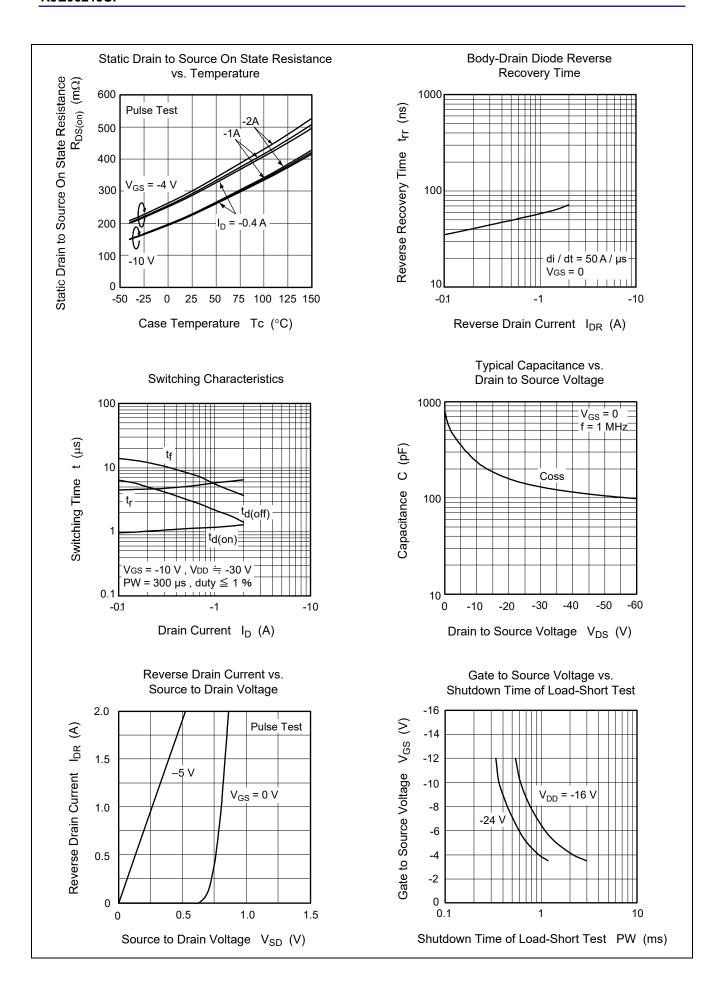
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	ΙD	-0.8	_		Α	$V_{GS} = -3 \text{ V}, V_{DS} = -10 \text{ V}^{\text{Note 6}}$
	ΙD		_	-40	mA	V _{GS} = -1.2 V, V _{DS} = -10 V
	ΙD	-3	_	_	Α	V _{GS} = -12 V, V _{DS} = -1.35 V Note6
	ΙD	-2	_	_	Α	V _{GS} = -12 V, V _{DS} = -10 Note 6
Drain to source breakdown	V _{(BR)DSS}	-60	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
voltage						
Gate to source breakdown	V _{(BR)GSS}	-16	_	_	V	$I_G = -800 \mu A, V_{DS} = 0$
voltage	V _{(BR)GSS}	2.5	_	_	V	$I_G = 100 \mu A, V_{DS} = 0$
Gate to source leak current	Igss		_	-100	μΑ	V _{GS} = -8 V, V _{DS} = 0
	Igss	_	_	-50	μΑ	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
	Igss	_	_	-10	μΑ	$V_{GS} = -1.2 \text{ V}, V_{DS} = 0$
	Igss	_	_	100	μА	V _{GS} = 2.4 V, V _{DS} = 0
Input current (shut down)	I _{GS(OP)}		-0.8	_	mA	V _{GS} = -8 V, V _{DS} = 0
	I _{GS(OP)}	_	-0.35	_	mA	$V_{GS} = -3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}		_	-10	μΑ	V _{DS} = -60 V, V _{GS} = 0
	I _{DSS}		_	-10	μΑ	V _{DS} = -48 V, V _{GS} = 0
						Ta = 125°C
Gate to source cutoff voltage	V _{GS(off)}	-0.9	_	-2.1	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Forward transfer admittance	y _{fs}	1.5	2.7	1	S	$I_D = -1 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 6}}$
Static drain to source on state	R _{DS(on)}		376	800	mΩ	$I_D = -0.4 \text{ A}, V_{GS} = -3V^{\text{Note 6}}$
resistance	R _{DS(on)}		296	400	mΩ	$I_D = -1 A$, $V_{GS} = -4 V^{\text{Note 6}}$
	R _{DS(on)}		231	270	mΩ	$I_D = -1 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note 6}}$
Output capacitance	Coss		236	_	pF	$V_{DS} = -10 \text{ V}, V_{GS} = 0,$
						f = 1MHz
Turn-on delay time	t _{d(on)}		1.2	_	μS	$V_{GS} = -10 \text{ V}, I_{D} = -1 \text{ A},$
Rise time	t _r		5.1	_	μS	$R_L = 30 \Omega$
Turn-off delay time	$t_{d(off)}$	_	2.1	_	μS	
Fall time	t _f		5.6	_	μS	
Body-drain diode forward voltage	V_{DF}		-0.8	_	V	$I_F = -2 A$, $V_{GS} = 0$
Body-drain diode reverse	t _{rr}	_	70	_	ns	$I_F = -2 A, V_{GS} = 0$
recovery time						di _F /dt = 50 A/μs
Over load shut down	tos		1.4		ms	$V_{GS} = -5 \text{ V}, V_{DD} = -16 \text{ V}$
operation time Note 7						
Over load shut down	tos	_	0.7	_	ms	$V_{GS} = -5 \text{ V}, V_{DD} = -24 \text{ V}$
operation time Note 7						

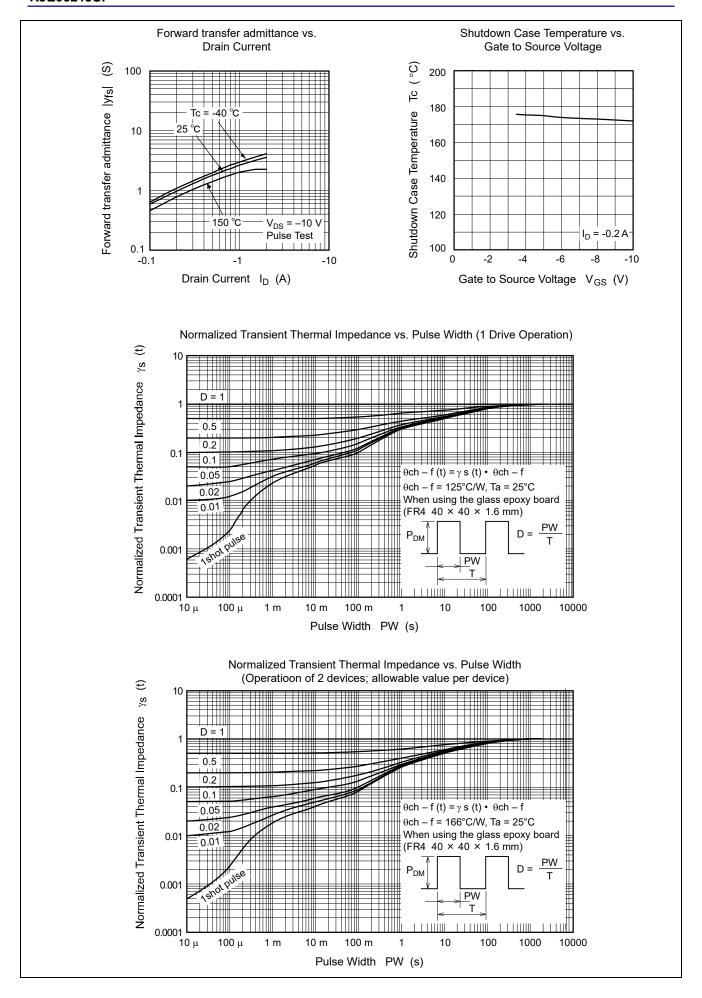
Notes: 6. Pulse test

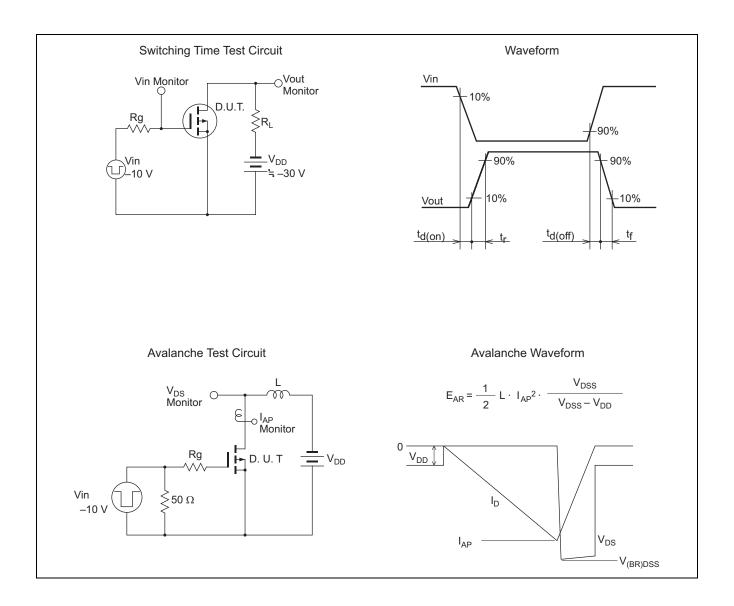
^{7.} Including the junction temperature rise of the over loaded condition.

Main Characteristics

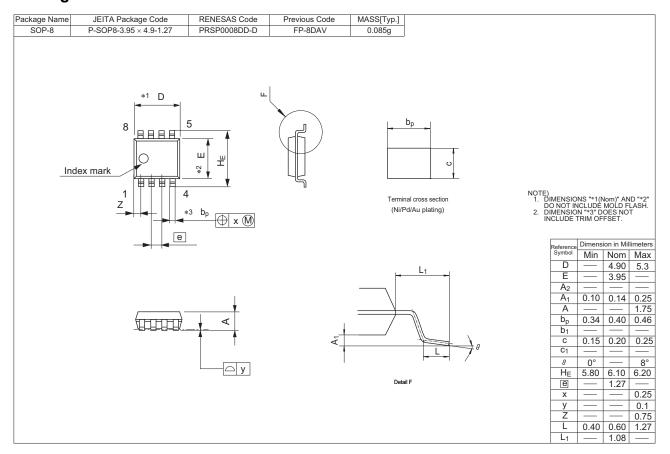








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJE0621JSP-00-J0	2500 pcs/reel	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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Renesas Electronics America Inc.

| Murphy Ranch Road, Milpitas, CA 95035, U.S.A. +1-408-432-8888, Fax: +1-408-434-5351

Renesas Electronics Canada Limited 9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3 Tel: +1-905-237-2004

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germar Tel: +49-211-6503-0, Fax: +49-211-6503-132

Renesas Electronics (China) Co., Ltd.
Room 1709 Quantum Plaza, No.27 ZhichunLu, Haidian District, Beijing, 100191 P. R. China Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd. Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai, 200333 P. R. China Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tel: +852-2265-6688, Fax: +852 2886-9022

Renesas Electronics Taiwan Co., Ltd.

13F, No. 363, Fu Shing North Road, Taipei 10543, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre, Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 1207, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics India Pvt. Ltd. No.777C, 100 Feet Road, HAL 2nd St

No.777C, 100 Feet Road, HAL 2nd Stage, Indiranagar, Bangalore 560 038, India Tel: +91-80-67208700, Fax: +91-80-67208777

Renesas Electronics Korea Co., Ltd. 17F, KAMCO Yangjae Tower, 262, Gangnam-daero, Gangnam-gu, Seoul, 06265 Korea Tel: +82-2-558-3737, Fax: +82-2-558-5338